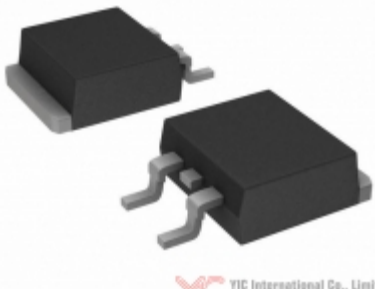

	<h2 style="color: red;">IPB100N06S3-04</h2>	
	Hersteller-Teilenummer:	IPB100N06S3-04
	Hersteller / Marke:	International Rectifier (Infineon Technologies)
	Teil der Beschreibung:	MOSFET N-CH 55V 100A TO-263
	Datenblätter:	 IPB100N06S3-04.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 13513 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	IPB100N06S3-04
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 55V 100A TO-263
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	13513 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	PG-TO263-3-2
Verlustleistung (max)	214W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	55V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	100A (Tc)
Rds On (Max) @ Id, Vgs	4.1 mOhm @ 80A, 10V
VGS (th) (Max) @ Id	4V @ 150µA
Gate Charge (Qg) (Max) @ Vgs	314nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	14230pF @ 25V
Verpackung	Tape & Reel (TR)

IPB100N06S3-04 ist neu im Original, Suche IPB100N06S3-04 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPB100N06S3-04 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPB100N06S3-04: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IPB100N06S2L05ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO263-3</p>	 <p>IPB100N06S2L-05 IPB100N06S2L-05 </p>	 <p>IPB100N08S2-07 INFINEO IPB100N08S2-07 INFINEO</p>	 <p>IPB100N06S3 Original TO-263</p>
 <p>IPB100N06S3-03 International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A D2PAK</p>	 <p>IPB100N06S3L-03 International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO263-3-2</p>	 <p>IPB100N08S2L-07 IPB100N08S2L-07 </p>	 <p>IPB100N08S207ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 75V 100A TO263-3</p>

heiße Teile

Mehr

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|-------------------|-------------------|------------------|-------------------|-------------------|
| ⊗ IPB08CNE8N | ↔ IPB08CNE8NG | ⇒ IPB090N06N3 | D IPB090N06N3G | ↔ IPB091N06NG |
| ⊣ IPB093N04LG | ⊗ IPB096N03L | D IPB096N03LG | ⇒ IPB097N08N3 | ↔ IPB097N08N3G |
| ⊗ IPB09N03 | ⊣ IPB09N03LA | ⊗ IPB09N03LAG | ↔ IPB09N03LAT | ↔ IPB100N04S2-04 |
| D IPB100N04S2L-03 | ⊗ IPB100N04S3 | ⊣ IPB100N04S3-03 | ⊗ IPB100N04S3-03M | ↔ IPB100N04S4-02D |
| ⇒ IPB100N04S4-03D | ↔ IPB100N04S4-H2 | ⊗ IPB100N06S2-05 | ⊣ IPB100N06S2L-05 | ↔ IPB100N06S3-03 |
| ↔ IPB100N06S3L-03 | ⇒ IPB100N06S3L-04 | D IPB100N08S2-07 | ⊗ IPB100N08S2L-07 | ⊣ IPB100N10S3-05 |
| ⊗ IPB107N20N3G | D IPB10N03L | ⇒ IPB10N03LB | ↔ IPB10N03LBG | ↔ IPB110N06L |
| ⊣ IPB110N06LG | ⊗ IPB114N03L | ↔ IPB114N03LG | ⇒ IPB11N03LAG | ↔ IPB11N60S5 |
| ⊗ IPB120N04S3-02 | ⊣ IPB120N04S4-01 | ⊗ IPB120N04S4-02 | D IPB120N06NG | ↔ IPB120N06S4 |
| ↔ IPB120N06S4-02 | ⊗ IPB120N06S4-03 | ⊣ IPB120N06S4-H1 | ⊗ IPB120P04L03 | ↔ IPB120P04P4L-03 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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